

捷多邦,专业PCB打样工厂,24小时加**SN74**AUC16374 16-BIT EDGE-TRIGGERED D-TYPE FLIP-FLOP WITH 3-STATE OUTPUTS

SCES403D-JULY 2002-REVISED JUNE 2005

FEATURES

- Member of the Texas Instruments Widebus™ Family
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode
 Operation
- Sub-1-V Operable
- Max t_{pd} of 2 ns at 1.8 V
- Low Power Consumption, 20-μA Max I_{cc}
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This 16-bit edge-triggered D-type flip-flop is operational at 0.8-V to 2.7-V V_{CC} , but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC16374 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. It can be used as two 8-bit flip-flops or one 16-bit flip-flop. On the positive transition of the clock (CLK) input, the Q outputs of the flip-flop take on the logic levels set up at the data (D) inputs.

| | DGG OR DGV PACKAGE (TOP VIEW) | | | | | | | |
|-------------------|----------------------------------|----|-------------------|--|--|--|--|--|
| _ | \Box | | 1000 | | | | | |
| 1 <u>0</u> [| 1 | 48 |] 1CLK | | | | | |
| 1Q1 [| 2 | 47 |] 1D1 | | | | | |
| 1Q2 | 3 | 46 |] 1D2 | | | | | |
| GND | 4 | 45 |] GND | | | | | |
| 1Q3 [| 5 | 44 |] 1D3 | | | | | |
| 1Q4 🛛 | 6 | 43 |] 1D4 | | | | | |
| V _{CC} [| 7 | 42 |] V _{CC} | | | | | |
| 1Q5 [| 8 | 41 |] 1D5 | | | | | |
| 1Q6 🛛 | 9 | 40 |] 1D6 | | | | | |
| GND [| 10 | 39 |] GND | | | | | |
| 1Q7 [| 11 | 38 |] 1D7 | | | | | |
| 1Q8 [| 12 | 37 |] 1D8 | | | | | |
| 2Q1 | 13 | 36 | 2D10 | | | | | |
| 2Q2 | 14 | 35 | 2D2 | | | | | |
| GND | 15 | 34 | GND | | | | | |
| 2Q3 [| 16 | 33 | 2D3 | | | | | |
| 2Q4 [| 17 | 32 | 2D4 | | | | | |
| V _{CC} | 18 | 31 | l v _{cc} | | | | | |
| 2Q5 [| 19 | 30 | 2D5 | | | | | |
| 2Q6 [| 20 | 29 | 2D6 | | | | | |
| GND | 21 | 28 | GND | | | | | |
| 2Q7 [| 22 | 27 | 2D7 | | | | | |
| 2Q8 | 23 | 26 | 2D8 | | | | | |
| 2 0E | 24 | 25 | 2CLK | | | | | |
| | 10 | _ | nZSC.0- | | | | | |
| | | | | | | | | |
| | | | | | | | | |

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

| T _A | PACKAGE | (1) | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|----------------------------|---------------|-----------------------|------------------|
| | TSSOP – DGG | Tape and reel | SN74AUC16374DGGR | AUC16374 |
| –40°C to 85°C | TVSOP – DGV | Tape and reel | SN74AUC16374DGVR | MH374 |
| | VFBGA – GQL ⁽²⁾ | Tape and reel | SN74AUC16374GQLR | MH374 |

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) Package preview

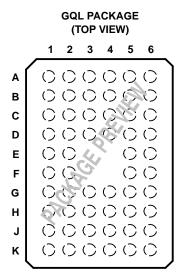
Prease be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



| | TERMINAL ASSIGNMENTS(" | | | | | | | | | |
|---|------------------------|-----|-----------------|-----------------|-----|------|--|--|--|--|
| | 1 2 3 4 5 | | | | | | | | | |
| Α | 1 0E | NC | NC | NC | NC | 1CLK | | | | |
| в | 1Q2 | 1Q1 | GND | GND | 1D1 | 1D2 | | | | |
| С | 1Q4 | 1Q3 | V _{CC} | V _{CC} | 1D3 | 1D4 | | | | |
| D | 1Q6 | 1Q5 | GND | GND | 1D5 | 1D6 | | | | |
| Е | 1Q8 | 1Q7 | | | 1D7 | 1D8 | | | | |
| F | 2Q1 | 2Q2 | | | 2D2 | 2D1 | | | | |
| G | 2Q3 | 2Q4 | GND | GND | 2D4 | 2D3 | | | | |
| н | 2Q5 | 2Q6 | V _{CC} | V _{CC} | 2D6 | 2D5 | | | | |
| J | 2Q7 | 2Q8 | GND | GND | 2D8 | 2D7 | | | | |
| κ | 2 <mark>0E</mark> | NC | NC | NC | NC | 2CLK | | | | |

TERMINAL ASSIGNMENTS⁽¹⁾

TEXAS STRUMENTS

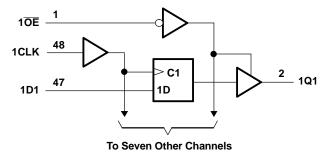
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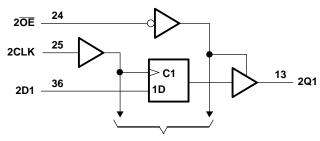
(1) NC - No internal connection

FUNCTION TABLE (EACH FLIP-FLOP)

| | INPUTS | OUTPUT | |
|----|------------|--------|-----------------------|
| OE | CLK | D | Q |
| L | \uparrow | Н | Н |
| L | \uparrow | L | L |
| L | H or L | Х | Q ₀ |
| н | Х | Х | Z |

LOGIC DIAGRAM (POSITIVE LOGIC)





To Seven Other Channels

Pin numbers shown are for the DGG and DGV packages.



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|------------------|--|--|------|-----------------------|------|
| V _{CC} | Supply voltage range | | -0.5 | 3.6 | V |
| VI | Input voltage range ⁽²⁾ | | -0.5 | 3.6 | V |
| Vo | Voltage range applied to any output in the I | nigh-impedance or power-off state ⁽²⁾ | -0.5 | 3.6 | V |
| Vo | Output voltage range ⁽²⁾ | | -0.5 | V _{CC} + 0.5 | V |
| I _{IK} | Input clamp current | V ₁ < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| I _O | Continuous output current | | | ±20 | mA |
| | Continuous current through V_{CC} or GND | | | ±100 | mA |
| | | DGG package | | 70 | |
| θ_{JA} | Package thermal impedance ⁽³⁾ | DGV package | | 58 | °C/W |
| | | GQL package | | 42 | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT |
|-----------------|------------------------------------|---|----------------------|----------------------|------|
| V _{CC} | Supply voltage | | 0.8 | 2.7 | V |
| | | V _{CC} = 0.8 V | V _{CC} | | |
| VIH | High-level input voltage | $V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$ | $0.65 \times V_{CC}$ | | V |
| | | V_{CC} = 2.3 V to 2.7 V | 1.7 | | |
| | | $V_{CC} = 0.8 V$ | | 0 | |
| V _{IL} | Low-level input voltage | V _{CC} = 1.1 V to 1.95 V | | $0.35 \times V_{CC}$ | V |
| | | V_{CC} = 2.3 V to 2.7 V | | 0.7 | |
| VI | Input voltage | | 0 | 3.6 | V |
| Vo | Output voltage | | 0 | V _{CC} | V |
| | | $V_{CC} = 0.8 V$ | | -0.7 | |
| | | High-level output current $V_{CC} = 1.1 \text{ V}$ $V_{CC} = 1.4 \text{ V}$ $V_{CC} = 1.65 \text{ V}$ | | -3 | |
| I _{OH} | High-level output current | | | -5 | mA |
| | | | | -8 | |
| | | $V_{CC} = 2.3 V$ | | -9 | |
| | | $V_{CC} = 0.8 V$ | | 0.7 | |
| | | V _{CC} = 1.1 V | | 3 | |
| I _{OL} | Low-level output current | V _{CC} = 1.4 V | | 5 | mA |
| | | V _{CC} = 1.65 V | | 8 | |
| | | V _{CC} = 2.3 V | | 9 | |
| Δt/Δv | Input transition rise or fall rate | | | 20 | ns/V |
| T _A | Operating free-air temperature | | -40 | 85 | °C |

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V _{cc} | MIN TYP ⁽¹⁾ MAX | UNIT | |
|------------------|--|-----------------|----------------------------|-------|--|
| | $I_{OH} = -100 \ \mu A$ | 0.8 V to 2.7 V | V _{CC} – 0.1 | | |
| | I _{OH} = -0.7 mA | 0.8 V | 0.55 | | |
| N/ | $I_{OH} = -3 \text{ mA}$ | 1.1 V | 0.8 | V | |
| V _{OH} | I _{OH} = -5 mA | 1.4 V | 1 | v | |
| | I _{OH} = -8 mA | 1.65 V | 1.2 | | |
| | I _{OH} = -9 mA | 2.3 V | 1.8 | | |
| | I _{OL} = 100 μA | 0.8 V to 2.7 V | 0.2 | | |
| | I _{OL} = 0.7 mA | 0.8 V | 0.25 | 0.3 V | |
| N/ | $I_{OL} = 3 \text{ mA}$ | 1.1 V | 0.3 | | |
| V _{OL} | $I_{OL} = 5 \text{ mA}$ | 1.4 V | 0.4 | v | |
| | $I_{OL} = 8 \text{ mA}$ | 1.65 V | 0.45 | | |
| | I _{OL} = 9 mA | 2.3 V | 0.6 | | |
| II All inputs | $V_{I} = V_{CC}$ or GND | 0 to 2.7 V | ±5 | μA | |
| l _{off} | V_{I} or V_{O} = 2.7 V | 0 | ±10 | μA | |
| I _{OZ} | $V_{O} = V_{CC}$ or GND | 2.7 V | ±10 | μA | |
| I _{CC} | $V_{I} = V_{CC} \text{ or GND},$ $I_{O} = 0$ | 0.8 V to 2.7 V | 20 | μA | |
| Ci | $V_{I} = V_{CC}$ or GND | 2.5 V | 3 | pF | |
| Co | $V_{O} = V_{CC}$ or GND | 2.5 V | 5 | pF | |

TEXAS INSTRUMENTS

www.ti.com

(1) All typical values are at $T_A = 25^{\circ}C$.

Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| | | V _{CC} = 0.8 V | V _{CC} = ± 0.7 | 1.2 V 1 V | V _{CC} = ± 0.7 | | V _{CC} = ± 0.1 | | V _{CC} = 2 ± 0.2 | | UNIT |
|--------------------|--|-------------------------|----------------------------|--------------|----------------------------|-----|----------------------------|-----|------------------------------|-----|------|
| | | TYP | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| f _{clock} | Clock frequency | 85 | | 250 | | 250 | | 250 | | 250 | MHz |
| tw | Pulse duration, CLK high or low | 5.9 | 1.9 | | 1.9 | | 1.9 | | 1.9 | | ns |
| t _{su} | Setup time, data before CLK [↑] | 1.4 | 1.2 | | 0.7 | | 0.6 | | 0.6 | | ns |
| t _h | Hold time, data after CLK [↑] | 0.1 | 0.4 | | 0.4 | | 0.4 | | 0.4 | | ns |

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = 0.8 V | V _{CC} = ± 0. | 1.2 V 1 V | | 1.5 V 1 V | | _c = 1.8 0.15 \ | | V _{CC} = ± 0. | | UNIT |
|------------------|-----------------|----------------|-------------------------|---------------------------|--------------|-----|--------------|-----|------------------------------|-----|---------------------------|-----|------|
| | (INPOT) | (001901) | TYP | MIN | MAX | MIN | MAX | MIN | TYP | MAX | MIN | MAX | |
| f _{max} | | | 85 | 250 | | 250 | | 250 | | | 250 | | MHz |
| t _{pd} | CLK | Q | 7.3 | 1 | 4.5 | 0.8 | 2.9 | 0.7 | 1.5 | 2.8 | 0.7 | 2.2 | ns |
| t _{en} | OE | Q | 7 | 1.2 | 5.3 | 0.8 | 3.6 | 0.8 | 1.5 | 2.9 | 0.7 | 2.2 | ns |
| t _{dis} | OE | Q | 8.2 | 2 | 7.1 | 1 | 4.8 | 1.4 | 2.7 | 4.5 | 0.5 | 2.2 | ns |



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Operating Characteristics⁽¹⁾

 $T_A = 25^{\circ}C$

| | PARAMETER | | TEST | V _{CC} = 0.8 V | V _{CC} = 1.2 V | $V_{CC} = 1.5 V$ | V _{CC} = 1.8 V | V _{CC} = 2.5 V | UNIT |
|--|-------------------------------------|---|--|-------------------------|-------------------------|------------------|-------------------------|-------------------------|------|
| | FARAMETER | | CONDITIONS | TYP | TYP | TYP TYP | | TYP | UNIT |
| C _{pd} (each output) ⁽²⁾ | Power dissipation capacitance | Outputs enabled, 1 output switching | $ \begin{array}{l} 1 \ f_{data} = 5 \ \text{MHz}, \\ 1 \ f_{clk} = 10 \ \text{MHz}, \\ 1 \ f_{out} = 5 \ \text{MHz}, \\ \hline \textbf{OE} = \textbf{GND}, \\ \textbf{C}_L = 0 \ \text{pF} \end{array} $ | 24 | 24 | 24.1 | 26.2 | 31.2 | pF |
| C _{pd(Z)} | Power dissipation capacitance | Outputs disabled, 1 clock and 1 data switching | $\begin{array}{l} 1 \ f_{data} = 5 \ \text{MHz}, \\ 1 \ f_{clk} = 10 \ \text{MHz}, \\ f_{out} = not \\ switching, \\ \overline{\text{OE}} = V_{CC}, \\ C_L = 0 \ \text{pF} \end{array}$ | 7.5 | 7.5 | 8 | 9.4 | 13.2 | pF |
| C _{pd} (each clock) ⁽³⁾ | Power dissipation capacitance | Outputs disabled, clock only switching | $\begin{array}{l} 1 \ f_{data} = 0 \ \text{MHz}, \\ 1 \ f_{clk} = 10 \ \text{MHz}, \\ f_{out} = not \\ switching, \\ \overline{\text{OE}} = V_{CC}, \\ C_L = 0 \ \text{pF} \end{array}$ | 13.8 | 13.8 | 14 | 14.7 | 17.5 | pF |

Total device C_{pd} for multiple (n) outputs switching and (y) clocks inputs switching = {n * C_{pd} (each output)} + {y * C_{pd} (each clock)}
 C_{pd} (each output) is the C_{pd} for each data bit (input and output circuitry) as it operates at 5 MHz (Note: the clock is operating at 10 MHz in this test, but its I_{CC} component has been subtracted out).
 C_{pd} (each clock) is the C_{pd} for the clock circuitry only as it operates at 10 MHz.

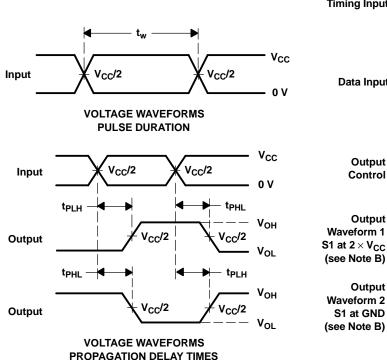
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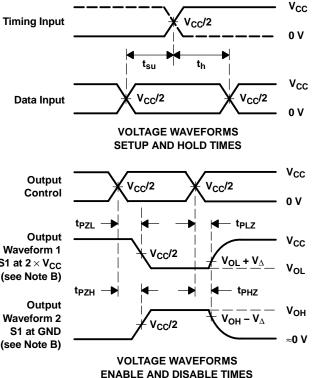


PARAMETER MEASUREMENT INFORMATION $\odot 2 \times V_{CC}$ **S**1 O Open RL From Output GND Under Test 0 CL RL (see Note A) LOAD CIRCUIT

| TEST | S1 |
|------------------------------------|-------------------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | $2 \times V_{CC}$ |
| t _{PHZ} /t _{PZH} | GND |
| | |

| V _{CC} | CL | RL | V_{Δ} |
|-------------------------------------|-------|--------------|--------------|
| 0.8 V | 15 pF | 2 k Ω | 0.1 V |
| 1.2 V \pm 0.1 V | 15 pF | 2 k Ω | 0.1 V |
| 1.5 V \pm 0.1 V | 15 pF | 2 k Ω | 0.1 V |
| 1.8 V \pm 0.15 V | 30 pF | 1 k Ω | 0.15 V |
| $\textbf{2.5 V} \pm \textbf{0.2 V}$ | 30 pF | 500 Ω | 0.15 V |





LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.

INVERTING AND NONINVERTING OUTPUTS

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , slew rate \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

4-Oct-2005

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|------------------|-----------------------|-----------------|--------------------|------|----------------|----------------------------|------------------|------------------------------|
| 74AUC16374DGGRE4 | ACTIVE | TSSOP | DGG | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| 74AUC16374DGVRE4 | ACTIVE | TVSOP | DGV | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUC16374DGGR | ACTIVE | TSSOP | DGG | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUC16374DGVR | ACTIVE | TVSOP | DGV | 48 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74AUC16374GQLR | ACTIVE | VFBGA | GQL | 56 | 1000 | TBD | SNPB | Level-1-240C-UNLIM |
| SN74AUC16374ZQLR | ACTIVE | VFBGA | ZQL | 56 | 1000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

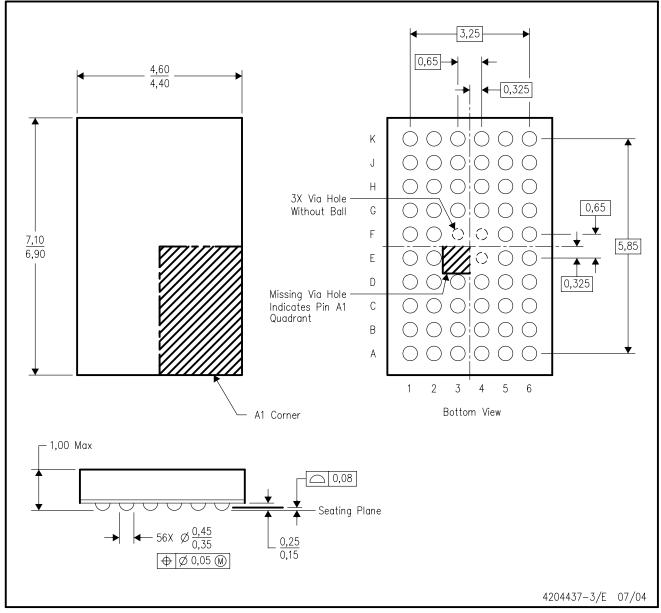
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

A. All linear dimensions are in millimeters.

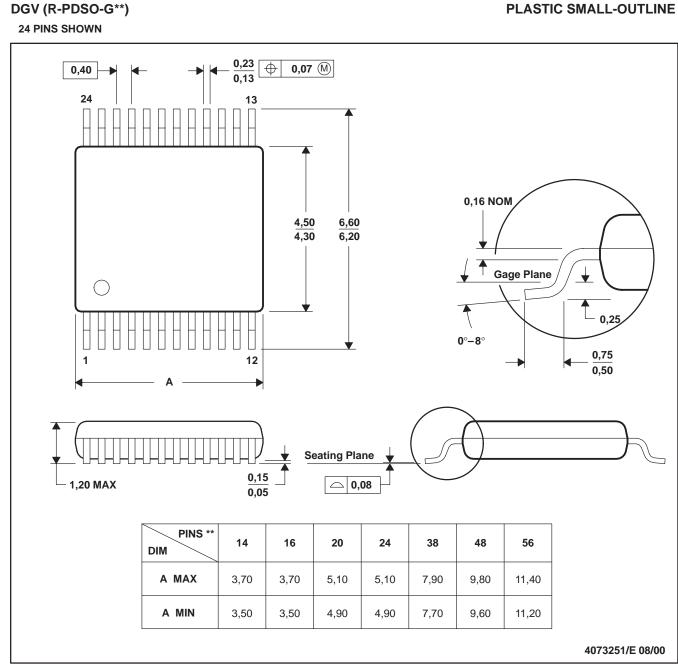
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



MECHANICAL DATA

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

PLASTIC SMALL-OUTLINE



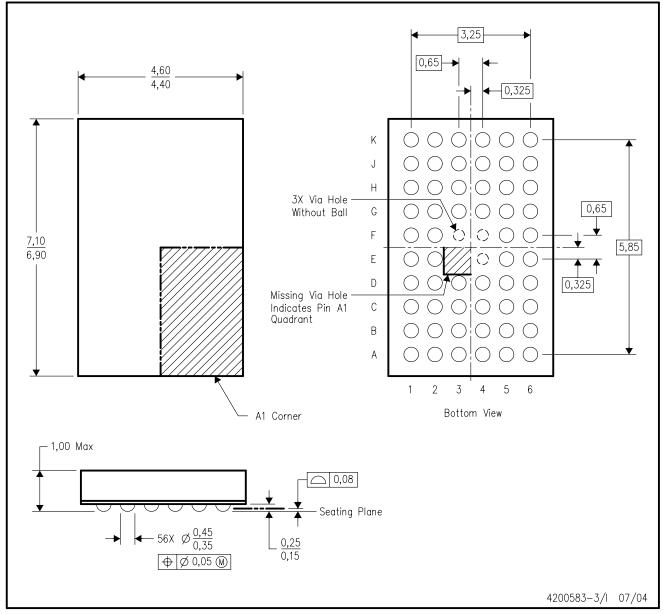
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153
 - 14/16/20/56 Pins MO-194



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.

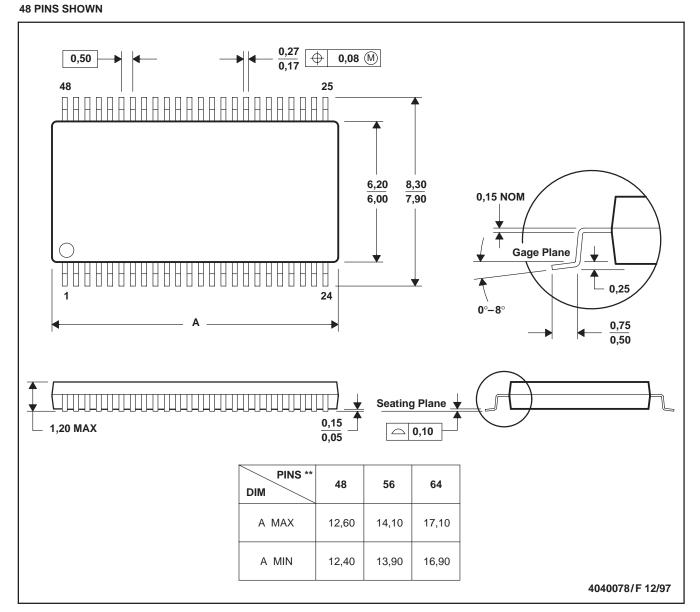


MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

PLASTIC SMALL-OUTLINE PACKAGE

DGG (R-PDSO-G**)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153



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